



DMN4020LFDEQ

Product Summary

BV _{DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
40)/	$21m\Omega @ V_{GS} = 10V$	8.6A
40V	28mΩ @ V _{GS} = 4.5V	6.9A

40V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Low On-Resistance

Mechanical Data

Case: U-DFN2020-6

- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The DMN4020LFDEQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

Case Material: Molded Plastic, "Green" Molding Compound.

Terminals: Finish - NiPdAu over Copper Lead-Frame. Solderable

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020

per MIL-STD-202, Method 208 @ Weight: 0.0065 grams (Approximate)

https://www.diodes.com/guality/product-definitions/

Description and Applications

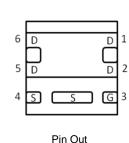
This MOSFET is designed to meet the stringent requirements of automotive applications. It is AEC-Q101 qualified, supported by a PPAP, and is ideal for use in:

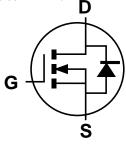
- General Purpose Interfacing Switch
- Power Management Functions

U-DFN2020-6 (Type E)



Bottom View





Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Quantity Per Reel
DMN4020LFDEQ-7	U-DFN2020-6 (Type E)	3,000
DMN4020LFDEQ-13	U-DFN2020-6 (Type E)	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

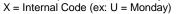
Marking Information



NE = Product Type Marking Code YWX = Date Code Marking

Y = Year (ex: 0 = 2020)

W = Week (ex: a = week 27; z represents week 52 and 53)



Date Code Key

Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	0	1	2	3	4	5	6	7	8	9	0	1
West 4.00					07.60							
Week	1-26			27-52 53								
Code		A-Z			a-z			Z				
Internal Code	Su	n	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	N N	N	Х		Y		Z



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Note 6) V_{GS} = 10V	I _D	8.6 6.9	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		I _{DM}	40	A
Maximum Body Diode Continuous Current		Is	8.6	A
Pulsed Body Diode Forward Current (10µs Pulse, I	I _{SM}	40	A	
Avalanche Current (Note 7) L = 0.1mH	I _{AS}	22.4	A	
Avalanche Energy (Note 7) L = 0.1mH	E _{AS}	25	mJ	

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)	T _A = +25°C	D	0.85	W	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.54	vv	
Thermal Resistance, Junction to Ambient (Note 5)	R ₀ JA	147.6	°C/W		
Total Power Dissipation (Note 6)	T _A = +25°C	Р	2.35	W	
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.5	vv	
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	53.3	°C/W		
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	6.9	C/W		
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C		

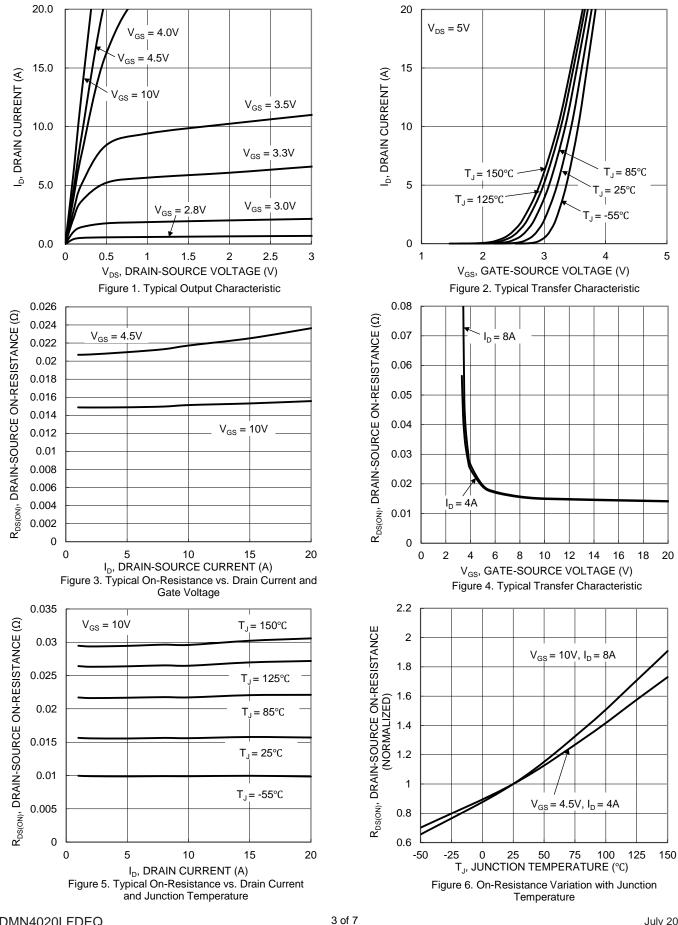
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Turn	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Symbol	IVIIII	Тур	Widx	Unit	Test condition
Drain-Source Breakdown Voltage	BV _{DSS}	40	_	_	V	V _{GS} = 0V, I _D = 250µA
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}		_	1	μA	$V_{DS} = 40V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)	1000			2.00		193 - 1201; 193 - 01
Gate Threshold Voltage	V _{GS(TH)}	1.4	_	2.4	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
			15	21		$V_{GS} = 10V, I_D = 8A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	20	28	mΩ	$V_{GS} = 4.5V, I_D = 4A$
Diode Forward Voltage	V _{SD}		0.7	1	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	_	1201	—	pF	
Output Capacitance	Coss	_	87	—	pF	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	58	_	pF	
Gate Resistance	Rq	_	1.3	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	12.7	—	nC	
Total Gate Charge (V _{GS} = 10V)	Qg	_	25.3	_	nC	
Gate-Source Charge	Qgs	_	5.6	—	nC	$V_{DS} = 20V, I_D = 8A$
Gate-Drain Charge	Q _{qd}	_	4.4	_	nC	7
Turn-On Delay Time	t _{D(ON)}		8	_	ns	
Turn-On Rise Time	t _R		2.6	—	ns	$V_{DS} = 20V, R_{L} = 2.5\Omega$
Turn-Off Delay Time	t _{D(OFF)}		17	—	ns	$V_{GS} = 10V, R_G = 3\Omega$
Turn-Off Fall Time	t _F		8.9	—	ns	7
Reverse Recovery Time	t _{RR}	_	17.5	_	ns	
Reverse Recovery Charge	Q _{RR}	_	8.9	_	nC	I _F = 8A, di/dt = 100A/μs

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square pad layout. 7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}$ C. 8. Short duration pulse test used to minimize self-heating effect. 9. Guaranteed by design. Not subject to production testing. Notes:



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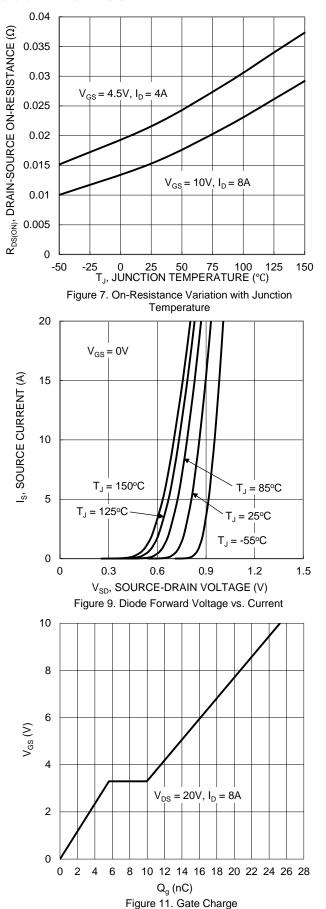


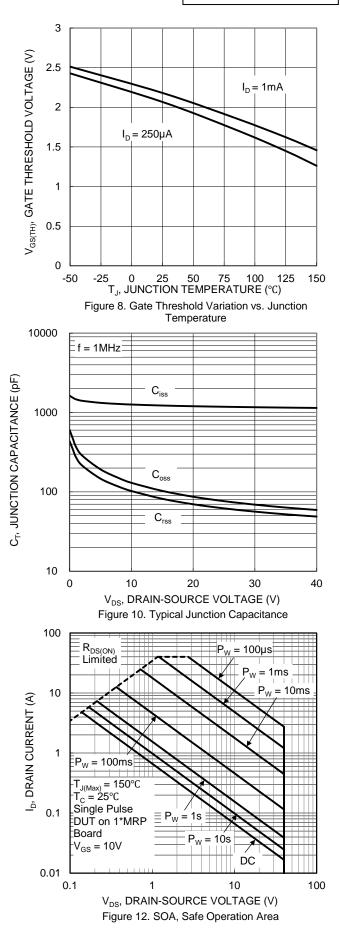
DMN4020LFDEQ Datasheet number: DS42203 Rev. 2 - 2

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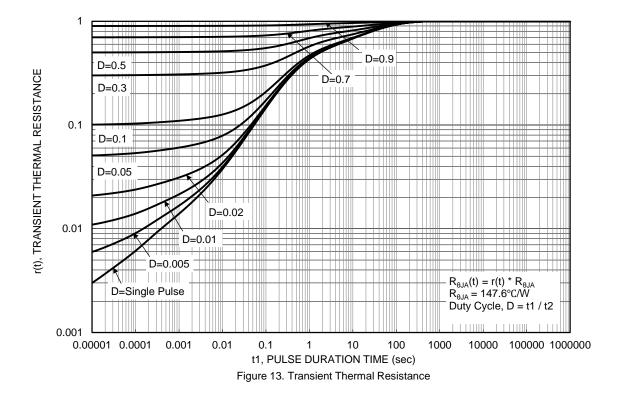
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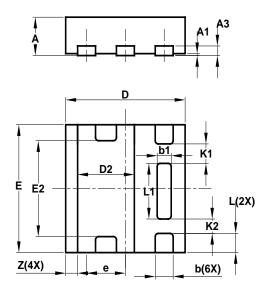






Package Outline Dimensions

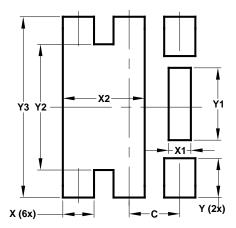
Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 Type E							
Dim	Min	Max	Тур				
Α	0.57	0.63	0.60				
A1	0	0.05	0.03				
A3			0.15				
b	0.25	0.35	0.30				
b1	0.185	0.285	0.235				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
E	1.95	2.05	2.00				
E2	1.40	1.60	1.50				
е			0.65				
L	0.25	0.35	0.30				
L1	0.82	0.92	0.87				
K1	_	_	0.305				
K2			0.225				
Z	_	_	0.20				
All	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value			
	(in mm)			
С	0.650			
Х	0.400			
X1	0.285			
X2	1.050			
Y	0.500			
Y1	0.920			
Y2	1.600			
Y3	2.300			



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